



# INDUSTRIAL AUTOMATED SYSTEMS “NIKA-PROFILE” AND TECHNOLOGIES FOR PRODUCTION SHAPED SAPPHIRE BY EFG (STEPANOV) TECHNIQUE

Equipment “NIKA-Profile” is intended for growing wide range of shaped sapphire crystals such as tubes, rods, plates and other profiles.

### Technical parameters

• Heating temperature	up to 2200° C
• Type of heating	Induction
• Crucible diameter	up to 250 mm
• Crystal weight	up to 16 kg
• Weight sensor sensitivity	0.05 g
• Upper shaft translation	850 mm 1050 mm
• Rate of upper shaft movement	0,01 - 140 mm/min
• Lower shaft translation	200 mm
• Rate of lower shaft movement	0,05 - 100 mm/min
• Type of power converter (generator)	IGBT
• Output power of generator	0,1 - 100 kW
• Precision of power control	0,003 kW
• Frequency	5-20 kHz
• Output power deviation	± 0,05%
• Gas pressure in chamber	up to 1,5x10 <sup>5</sup> Pa
• Limit vacuum in chamber	2.6 Pa 2*10 <sup>-3</sup> Pa
• Pressure of cooling water	200 - 250 kPa



### Equipment advantages:

- Crystals weight up to 16 kg.
- Automated seeding system.
- Automatic crystal growth control system which allows automatic tuning of the power regulator during crystallization process.
- End-to-end automation system for all stages of the crystal growing process.
- Vacuum long-stroke bellows for crystal pulling and crucible movement allows to minimize vacuum leakage .
- Precision motors for pulling crystal and crucible movement.
- High stable IGBT generator for induction heating with automated restart system.
- The highly cost-effective technology for producing sapphire protective screens for smartphones and other mobile devices has been created.
- Simultaneously growth of the 24 sapphire plates.
- Width of sapphire plates 90 mm, thickness from 1,4mm, length up to 1000 mm.
- Cycle time 16-20 h, crystals weight up to 16 kg.
- Cost of the screens made of EFG plate is 1.5-1.7 times lower than that screens cutted from ingots grown by the Kyropoulos technique.

